1. 半导体砷化镓(GaAs)是闪锌矿结构, Ga, As 原子在品胞中的位置分别为:

Ga (0,0,0)

(1/2,1/2,0)

(1/2,0,1/2)

(0,1/2,1/2)

As (1/4,1/4,1/4)

(3/4,3/4,1/4)

(3/4,1/4,3/4)

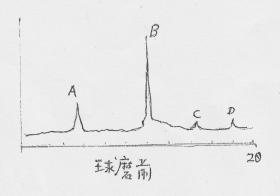
(1/4,3/4,3/4)

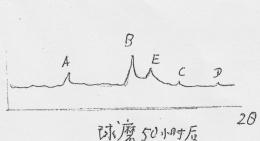
计算其结构因子 F (hkl), 并讨论其结构消光规律。

2. 金属 Nb 为体心立方晶体,晶格常数 a=0.329nm,有铜  $K_{\alpha}$  X 射线作 Nb 粉末衍射实验,列出可能存在的衍射峰的位置(即  $\theta$  值)及相应的衍射指数(hkl),计算前两个峰的相对强度。

3. 将 α-Fe (30%), Si (70%) 的混合粉末球磨 50 小时, 球磨前后的 X 射线粉末衍射花样 如下图所示。请标出各衍射峰的来源(物相, 衍射指数), 并讨论样品球磨前后的物相 变化。

α-Fe 为体心立方晶体, a=0.286nm; Si 为金刚石结构, a=0.543nm, X 射线用 Cu K<sub>α</sub>。





各衍射峰位置 A (2θ=28.4°)

B  $(20=44.8^{\circ})$ 

 $C(2\theta=56.2^{\circ})$ 

D  $(2\theta = 65.2^{\circ})$ 

E  $(2\theta = 49.2^{\circ})$ 

## 4. Patterson function of Tl atoms

We construct the Patterson function of Tl atoms as follows:

$$P(x) = \sum_{h=1}^{8} |F_{2,h}^{n}|^{2} \cos(2\pi hx/D), \qquad (15)$$

where D = 43.1 Å is the lamellar spacing. The function (Fig. 2) shows five distinct peaks on the Patterson coordinate, approximately at 0, 11.8, 18.7, 24.4, 31.3 Å. In order to interpret this pattern, let us consider a unit cell consisting of 20 DLPC molecules, 2 gramicidin monomers (which form one channel), 2 thallium acetate molecules and a number of water molecules. If the electron density of the unit cell is plotted on the x axis (normal to the plane of the membrane) with the origin set at the mid-plane of the bilayer, the cell will range from -D/2 to D/2and a centrosymmetric bilayer from -H/2 to H/2(H < D); from -D/2 to -H/2 and H/2 to D/2 is water; the gramicidin channel (whose length is less than H) is centrosymmetrically embedded in the bilayer. Thus the positions of Tl ions must also be symmetrically distributed; that is, potentially there are pairs of symmetric ion sites (x and -x) and unpaired sites at x = 0 and D/2 (equivalently -D/2).

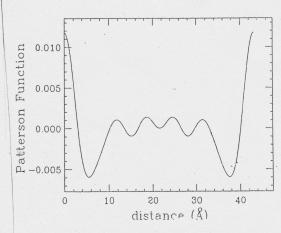


Fig. 2. The Patterson function of the Tl ions.

试确定下在学院的位置。